TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (U-MOSII)

2SK2986

DC-DC Converter, Relay Drive and Motor Drive Applications

• Low drain-source ON resistance : $R_{DS(ON)} = 4.5 \text{ m}\Omega \text{ (typ.)}$

• High forward transfer admittance : $|Y_{fs}| = 80 S (typ.)$

• Low leakage current : $I_{DSS} = 100 \mu A \text{ (max) (V}_{DS} = 60 \text{ V)}$

• Enhancement mode : V_{th} = 1.3 to 2.5 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	60	$(\nearrow \land)$
Drain-gate voltage (R _{GS} = 20 kΩ)		V_{DGR}	60	(W)
Gate-source voltage		V_{GSS}	±20	V
Drain current	DC (Note 1)	ΙD	55	
	Pulse (t≤10 s) (Note 1)	laa	70	A
	Pulse (t≤1 ms) (Note 1)	IDP	280	
Drain power dissipation (Tc = 25°C)		PD	100	∠ ⟨w
Single pulse avalanche energy (Note 2)		EAS	525	κ
Avalanche current		JAR	55	A
Repetitive avalanche energy (Note 3)		(EAR))	10	\/mJ
Channel temperature		Tch	150	~c
Storage temperature range		// T _{stg}	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	Rth (ch-c)	1.25	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	83.3	°C/W

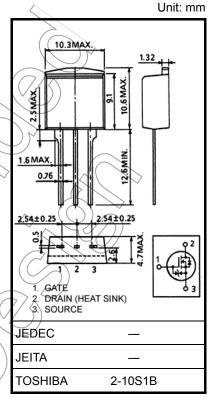
Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 25 V, T_{ch} = 25°C (initial), L = 236 μ H, I_{AR} = 55 A, R_G = 25 Ω

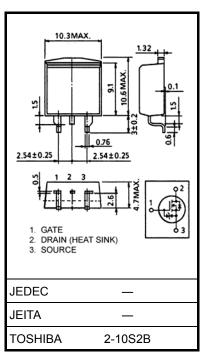
Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device.

Please handle with caution.



Weight: 1.5 g (typ.)



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Electrical Characteristics (Ta = 25°C)

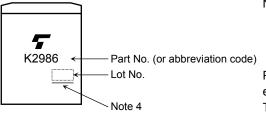
Charac	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	ırrent	I _{GSS}	V _{GS} = ±16 V, V _{DS} = 0 V	_	_	±10	μΑ
Drain cut-off cu	rrent	I _{DSS}	V _{DS} = 60 V, V _{GS} = 0 V	_	_	100	μA
Drain-source breakdown	V (BR) DSS	I _D = 10 mA, V _{GS} = 0 V	60	_	_	V	
voltage		V _{(BR) DSX}	I _D = 10 mA, V _{GS} = -20 V			_	v
Gate threshold v	/oltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	1,3) /~	2.5	V
Drain-source O	N registance	Dec (c)	V _{GS} = 10 V, I _D = 35 A	\nearrow	4.5	5.8	mΩ
Drain-source ON resistance		R _{DS} (ON)	V _{GS} = 4 V, I _D = 35 A))	5.8	10	11122
Forward transfe	r admittance	Y _{fs}	V _{DS} = 10 V, I _D = 35 A	40	80	_	S
Input capacitano	ce	C _{iss}		_	9300	_	
Reverse transfer capacitance Output capacitance		C _{rss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	910	_	pF
		Coss			1435	\rightarrow	
Switching time -	Rise time	t _r	V _{GS} OV ID=35A V _{OUT}	-	18	> _	
	Turn-on time	t _{on}	$^{\text{VGS}}$ $_{0\text{V}}$ $^{\text{L}}$ $^{\text{RL}}$ $^{\text{RL}}$		50	_	
	Fall time	t _f	V_{DD}		110	_	ns
	Turn-off time	t _{off}	Duty $\leq 1\%$, $t_{\rm w} = 10\mu {\rm s}$	_	480	_	
Total gate charg plus gate-drain)		Q _g (_	210	_	
Gate-source charge Qgs		Qgs	V _{DD} ≈ 48 V, V _{GS} = 10 V, I _D = 55 A	_	145	_	nC
Gate-drain ("mil	ller") Charge	Q _{gd}		_	65	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics Symbol Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	_	_	55	Α
Pulse drain reverse current t ≤ 10 s	_	_	70	A
(Note 1) IDRP t ≤ 1 ms	_	_	280	
Forward voltage (diode) V _{DSF} I _{DR} = 55 A, V _{GS} = 0 V		_	-1.5	V
Reverse recovery time		60		ns
Reverse recovery charge I _{DR} = 55 A, V _{GS} = 0 V, dI _{DR} / dt = 50 A		50	_	nC

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Marking

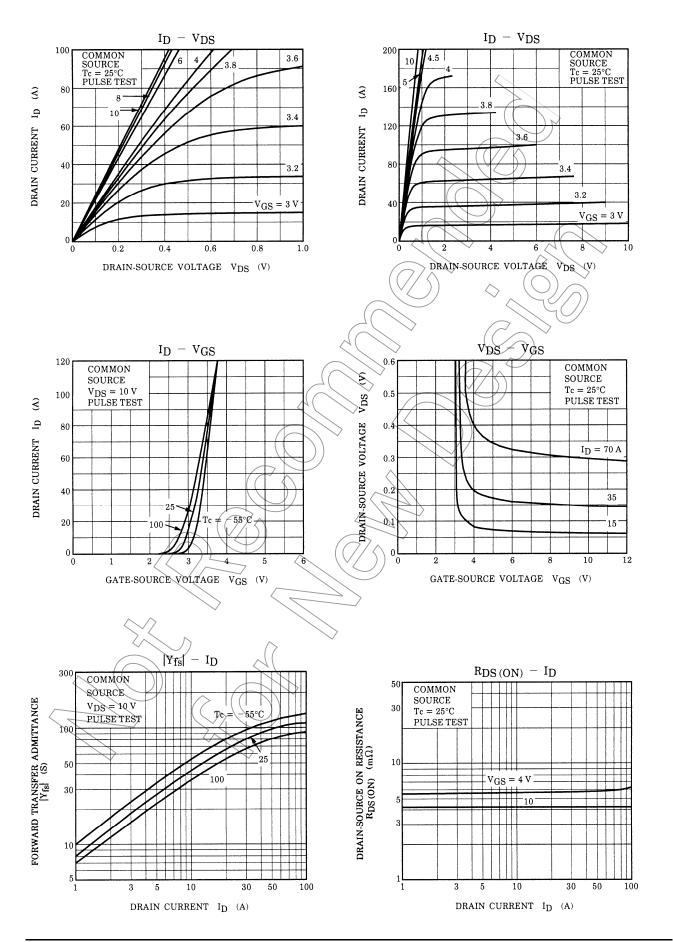


Note 4: A line under a Lot No. identifies the indication of product Labels.

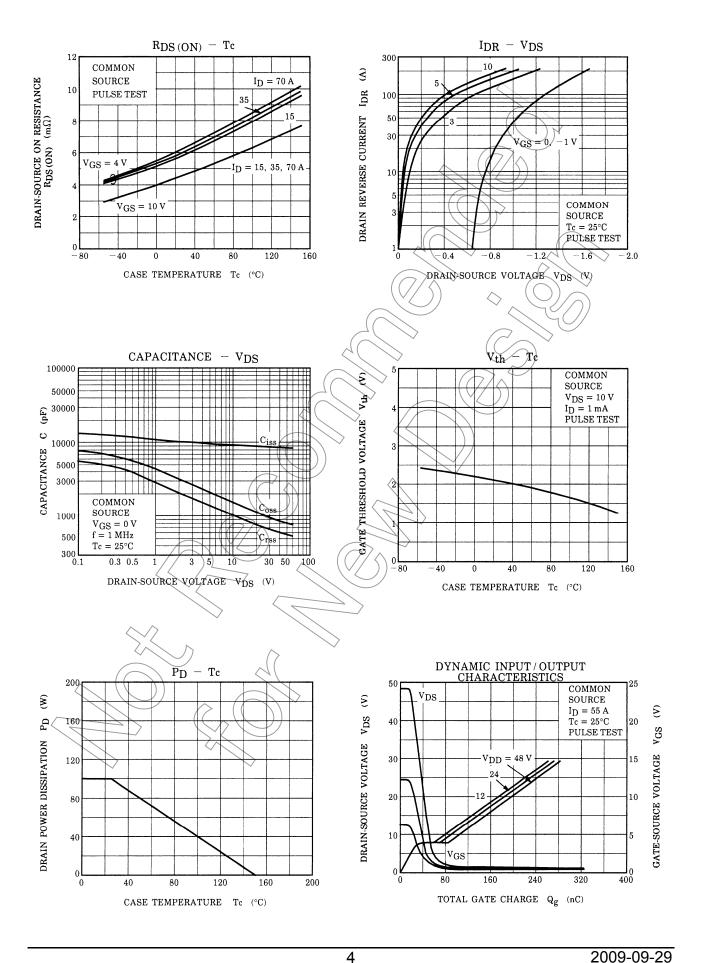
Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

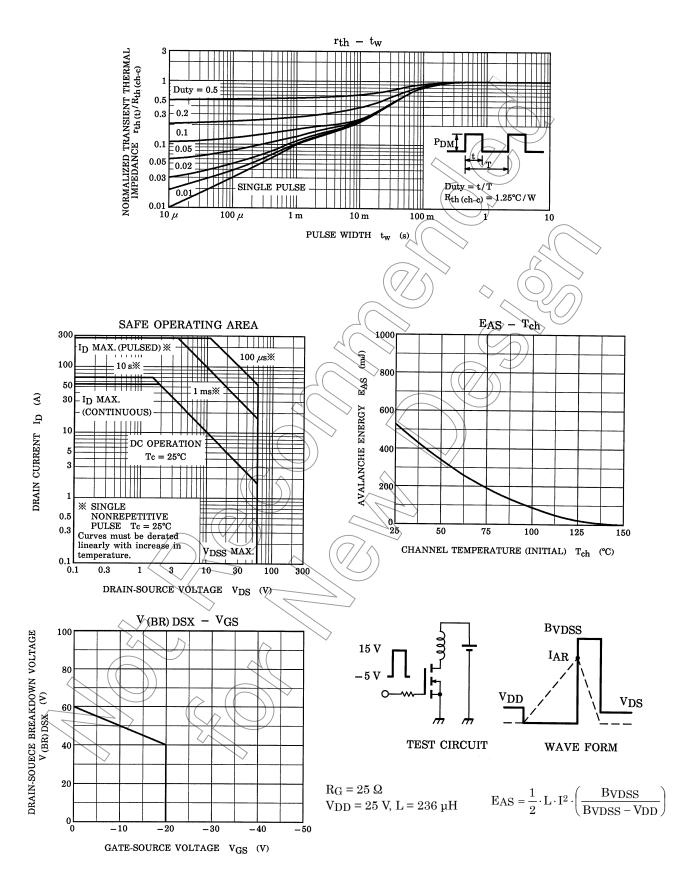
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament

and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.



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